

HD74HC95

8-bit Shift Register

REJ03D0558-0200
 (Previous ADE-205-431)
 Rev.2.00
 Oct 06, 2005

Description

This 4-bit register features parallel and serial inputs, parallel outputs, mode control, and two clock inputs. The register has three mode operation:

- Parallel (broadside) load
- Shift right (the direction Q_A toward Q_D)
- Shift left (the direction Q_D toward Q_A)

Parallel loading is accomplished by applying the four bits of data and taking the mode control input high. The data is loaded into the associated flip-flops and appears at the outputs after the high-to-low transition of the clock-2 input. During loading, the entry of serial data is inhibited. Shift right is accomplished on the high-to-low transition of clock-1 when the mode control is low; shift left is accomplished on the high-to-low transition of clock-2 when the mode control is high by connecting the output of each flip-flop (Q_D to input C, etc.) and serial data is entered at input D. The clock input may be applied commonly to clock-1 and clock-2 if both modes can be clocked from the same source. Changes at the mode control input should normally be made while both clock inputs are low; however, conditions described in the last three lines of the function table will also ensure that register contents are protected.

Features

- High Speed Operation: t_{pd} (Clock to Q) = 17 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC95P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	P	—
HD74HC95RPEL	SOP-14 pin (JEDEC)	PRSP0014DE-A (FP-14DNU)	RP	EL (2,500 pcs/reel)

Function Table

Mode Control	Inputs							Outputs			
	Clocks		Serial	Parallel							
	2 (L)	1 (R)		A	B	C	D	Q _A	Q _B	Q _C	Q _D
H	H	X	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
H		X	X	a	b	c	d	a	b	c	d
H		X	X	Q _{B+}	Q _{C+}	Q _{D+}	d	Q _{Bn}	Q _{Cn}	Q _{Dn}	d
L	L	H	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
L	X		H	X	X	X	X	H	Q _{An}	Q _{Bn}	Q _{Cn}
L	X		L	X	X	X	X	L	Q _{An}	Q _{Bn}	Q _{Cn}
	L	L	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
	L	L	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
	L	H	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
	H	L	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}
	H	H	X	X	X	X	X	Q _{A0}	Q _{B0}	Q _{C0}	Q _{D0}

Notes: 1. H : High level, L : Low level, X : Irrelevant

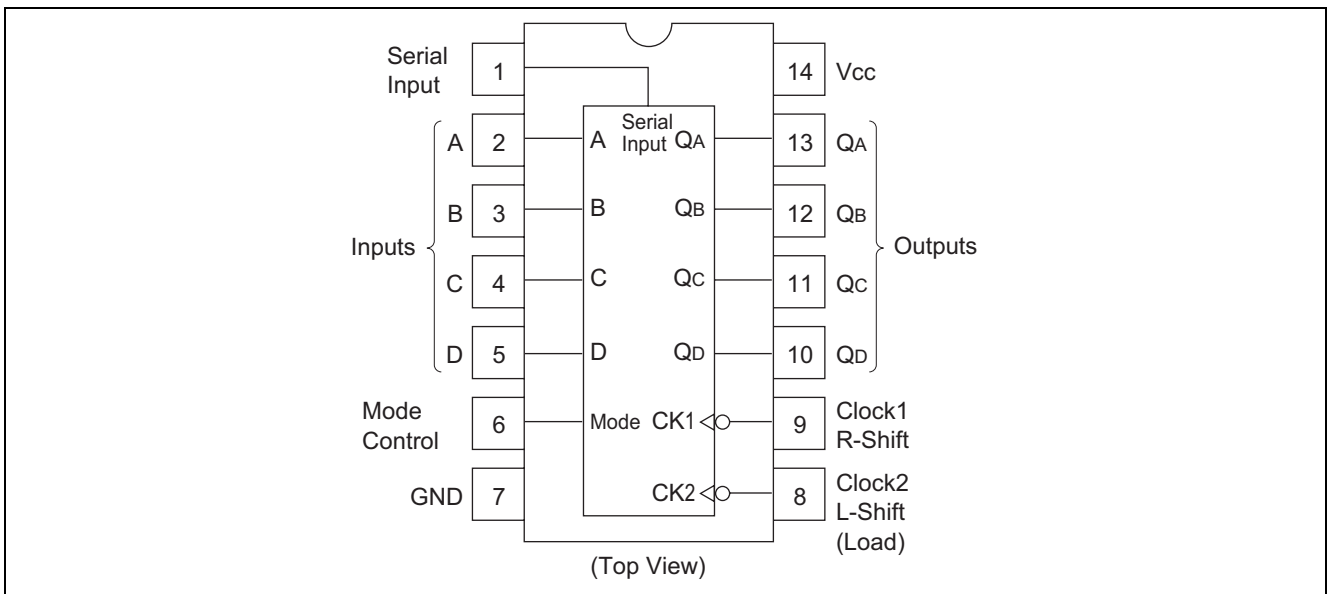
2. a to d : The level of steady-state input at inputs A, B, C or D respectively

3. Q_{A0} to Q_{D0} : The level of Q_A, Q_B, Q_C or Q_D respectively before the indicated steady-state input conditions were established.

4. Q_{An} to Q_{Dn} : The level of Q_A, Q_B, Q_C or Q_D respectively before the most-recent () transition of the clock.

5. + : Shifting left requires external connection of Q_B to A, Q_C to B and Q_D to C. Serial data is entered at input D.

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
Input / Output voltage	V_{in}, V_{out}	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	I_{IK}, I_{OK}	± 20	mA
Output current	I_O	± 25	mA
V_{CC} , GND current	I_{CC} or I_{GND}	± 50	mA
Power dissipation	P_T	500	mW
Storage temperature	T_{stg}	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	T_a	-40 to 85	°C	
Input rise / fall time *1	t_r, t_f	0 to 1000	ns	$V_{CC} = 2.0\text{ V}$
		0 to 500		$V_{CC} = 4.5\text{ V}$
		0 to 400		$V_{CC} = 6.0\text{ V}$

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

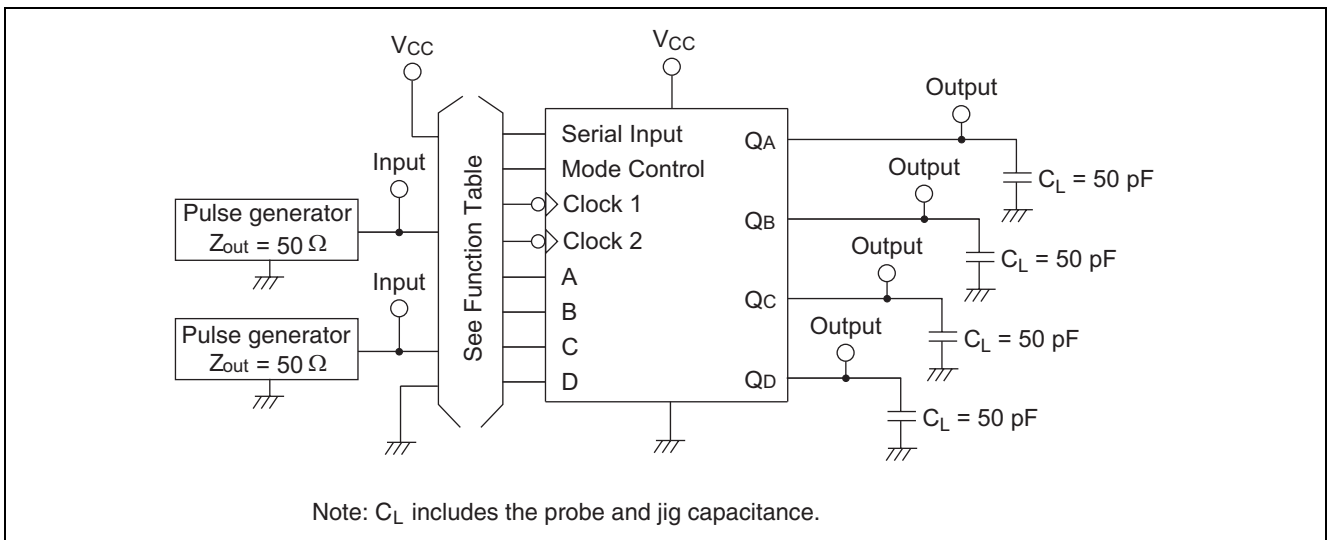
Electrical Characteristics

Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{ to }+85^\circ\text{C}$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OH} = -20\ \mu\text{A}$
		4.5	4.4	4.5	—	4.4	—			$I_{OH} = -4\ \text{mA}$
		6.0	5.9	6.0	—	5.9	—			$I_{OH} = -5.2\ \text{mA}$
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
		6.0	5.68	—	—	5.63	—			
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OL} = 20\ \mu\text{A}$
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			$I_{OL} = 4\ \text{mA}$
6.0	—	—	0.26	—	0.33		$I_{OL} = 5.2\ \text{mA}$			
Input current	I_{in}	6.0	—	—	± 0.1	—	± 1.0	μA	$V_{in} = V_{CC}$ or GND	
Quiescent supply current	I_{CC}	6.0	—	—	4.0	—	40	μA	$V_{in} = V_{CC}$ or GND, $I_{out} = 0\ \mu\text{A}$	

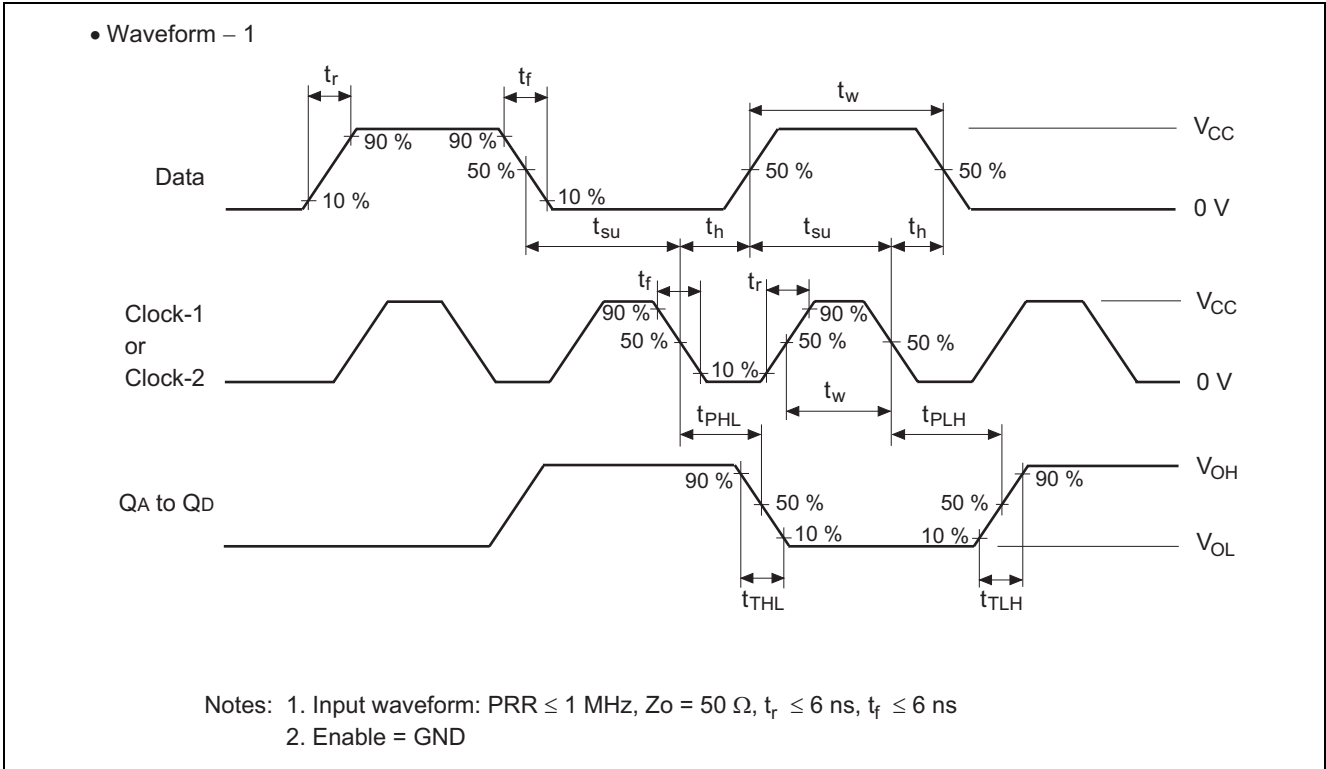
Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } +85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Maximum clock frequency	f_{max}	2.0	—	—	4	—	3	MHz	
		4.5	—	—	20	—	16		
		6.0	—	—	24	—	19		
Propagation delay time	t_{PLH}	2.0	—	—	145	—	180	ns	
		4.5	—	17	29	—	36		
		6.0	—	—	25	—	31		
	t_{PHL}	2.0	—	—	170	—	215	ns	
		4.5	—	17	34	—	43		
		6.0	—	—	29	—	37		
Pulse width	t_w	2.0	80	—	—	100	—	ns	Clock
		4.5	16	6	—	20	—		
		6.0	14	—	—	17	—		
Setup time	t_{su}	2.0	100	—	—	125	—	ns	
		4.5	20	2	—	25	—		
		6.0	17	—	—	21	—		
Hold time	t_h	2.0	10	—	—	10	—	ns	
		4.5	10	-1	—	10	—		
		6.0	10	—	—	10	—		
Output rise/fall time	t_{TLH}, t_{THL}	2.0	—	—	75	—	95	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	C_{in}	—	—	5	10	—	10	pF	

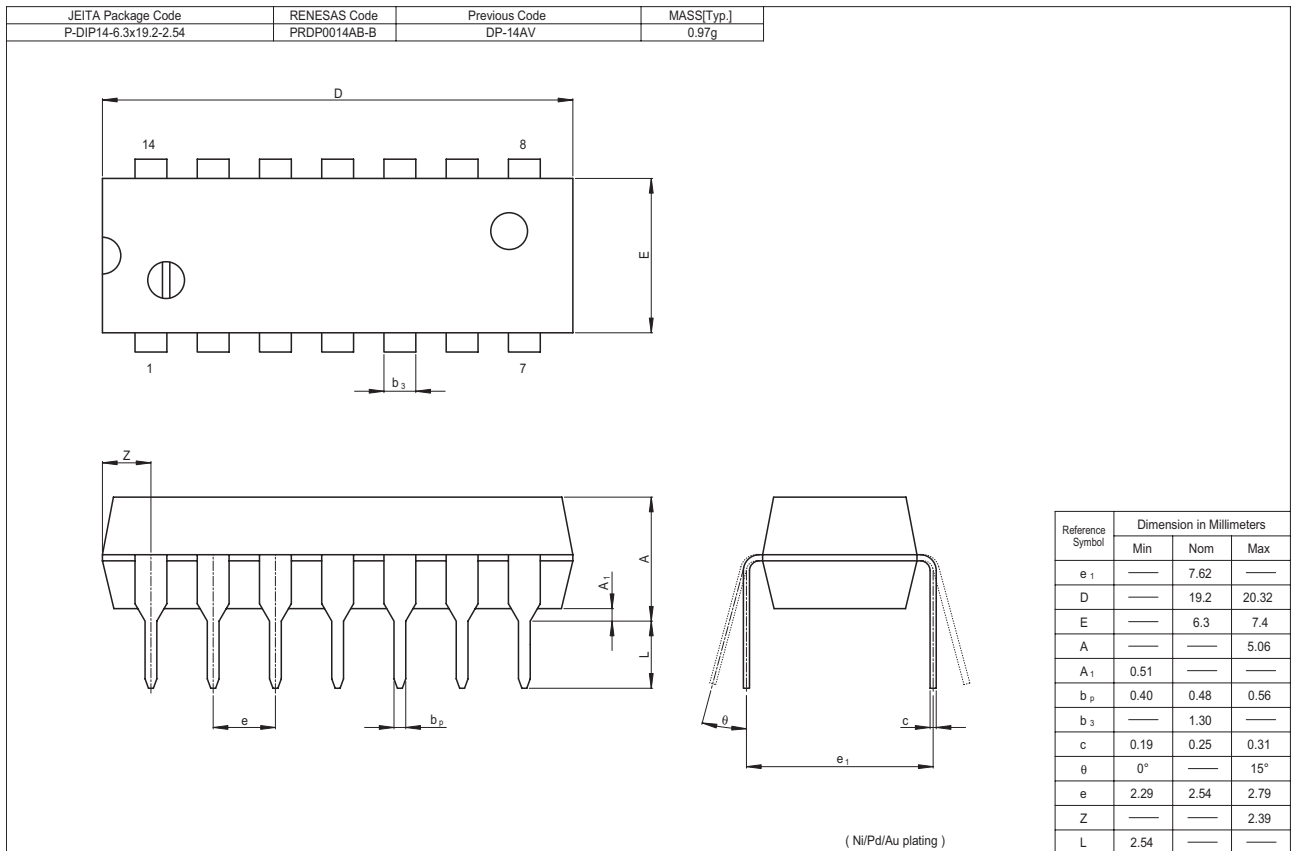
Test Circuit



Waveforms

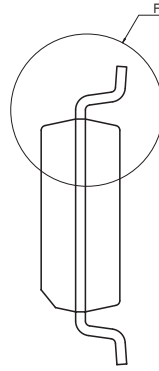
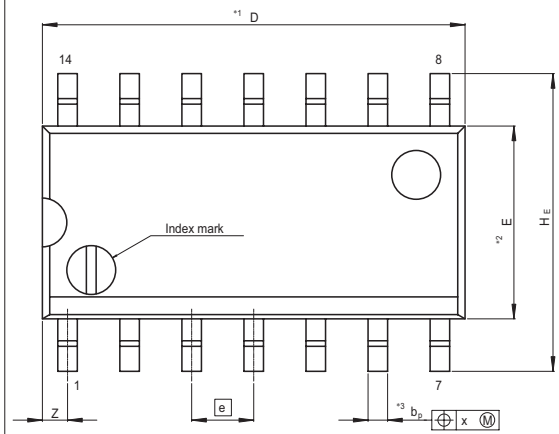


Package Dimensions

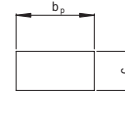


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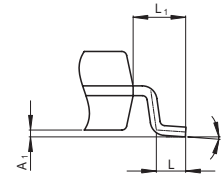
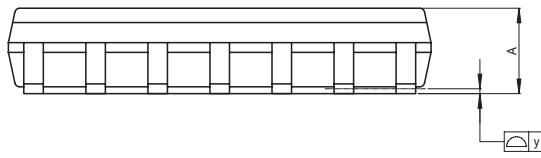
JEITA Package Code P-SOP14-3.95x8.65-1.27	RENESAS Code PRSP0014DE-A	Previous Code FP-14DNV	MASS[Typ.] 0.13g
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NOTE)
1. DIMENSIONS*1 (Nom)*AND*2*
DO NOT INCLUDE MOLD FLASH.
2. DIMENSION*3*DOES NOT
INCLUDE TRIM OFFSET.



Terminal cross section
(Ni/Pd/Au plating)



Detail F

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	8.65	9.05
E	—	3.95	—
A ₂	—	—	—
A ₁	0.10	0.14	0.25
A	—	—	1.75
b _p	0.34	0.40	0.46
b ₁	—	—	—
c	0.15	0.20	0.25
c ₁	—	—	—
θ	0°	—	8°
H _E	5.80	6.10	6.20
e	—	1.27	—
x	—	—	0.25
y	—	—	0.15
Z	—	—	0.635
L	0.40	0.60	1.27
L ₁	—	1.08	—

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